

Spezifikationen	
Artikelnummer	PSMN4R4-80PS,127
Hersteller	Nexperia
Beschreibung	MOSFET N-CH 80V 100A TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2660 pcs Stock
VGS (th) (Max) @ Id	4V @ 1mA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	TO-220AB
Serie	-
Rds On (Max) @ Id, Vgs	4.1 mOhm @ 15A, 10V
Verlustleistung (max)	306W (Tc)
Verpackung	Tube
Verpackung / Gehäuse	TO-220-3
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Eingabekapazität (Ciss) (Max) @ Vds	8400pF @ 40V
Gate Charge (Qg) (Max) @ Vgs	125nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	10V
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	100A (Tc)

sein:

PSMN4R4-80BS
NXP
PSMN4R4-80BS NXP



PSMN4R4-30MLC,115
Nexperia USA Inc.
MOSFET N-CH 30V 70A LFPAK33



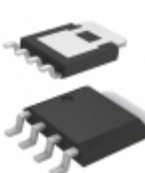
PSMN4R4-80BS,118
Nexperia USA Inc.
MOSFET N-CH 80V 100A D2PAK

PSMN4R5-30YLC ,115
NXP
NXP 2015+RoHS



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YXC International Co., Limited.

PSMN4R4-80PS
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PSMN4R4-80PS NXP



PSMN4R5-30YLC,115
Nexperia USA Inc.
MOSFET N-CH 30V 84A LFPAK



PSMN4R3-80PS,127
Nexperia USA Inc.
MOSFET N-CH 80V 120A
TO220AB

Mehr

PSMN4R4-80PS,127 Experia	PSMN4R4-80PS,127 Datenblatt	PSMN4R4-80PS,127-Datenblätter	PSMN4R4-80PS,127 PDF	Nexperia PSMN4R4-80PS,127
PSMN4R4-80PS,127 Electronic	PSMN4R4-80PS,127-Komponenten	PSMN4R4-80PS,127-Verteiler	PSMN4R4-80PS,127-Bild	PSMN4R4-80PS,127-Teil
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